FIG.1A

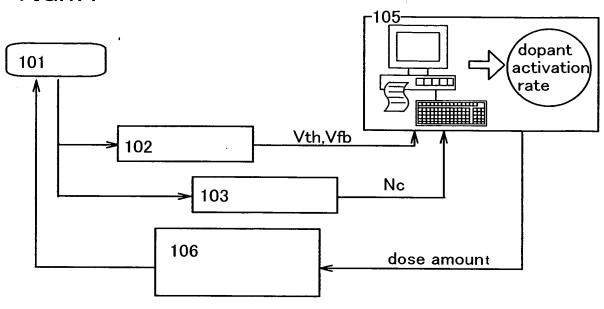


FIG.1B

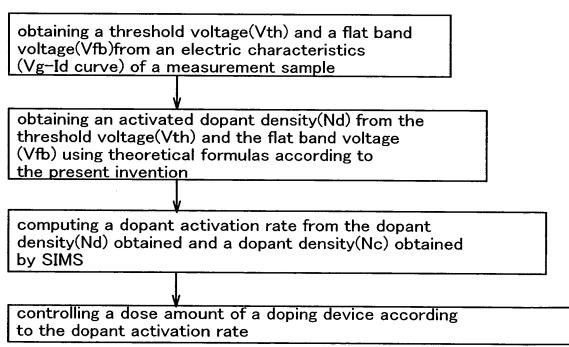


FIG.2A

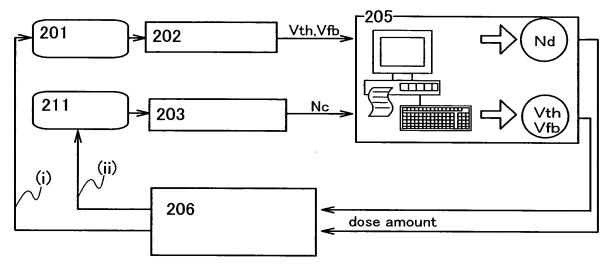
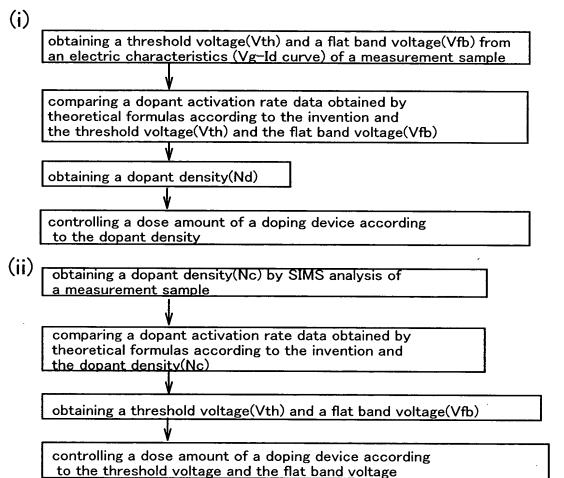


FIG.2B





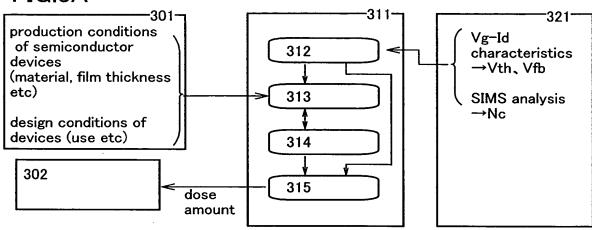


FIG.3B

inputting Vth, Vfb and Nc of a semiconductor device
obtaining Nd by computing means and computing a dopant activation rate(Nd/Nc)
setting a dose amount by a setting device and outputting to a doping device

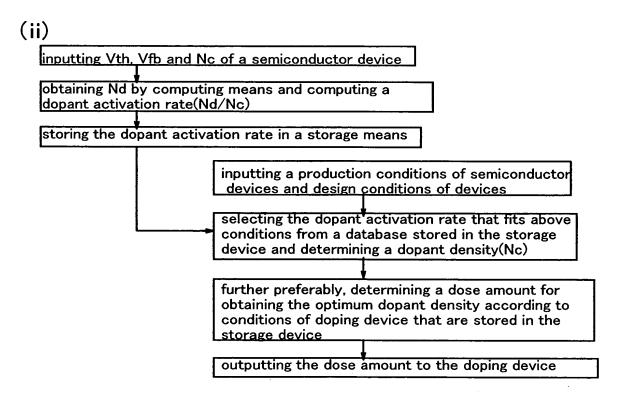


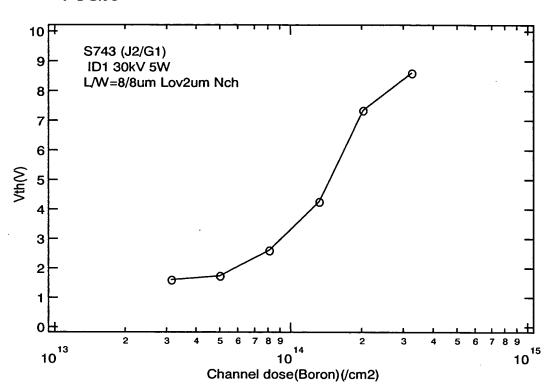
FIG.4A FIG.4B (i) 401 400 (ii) (iii) 402 (iv) ر404 - 403 complete 405 406 407

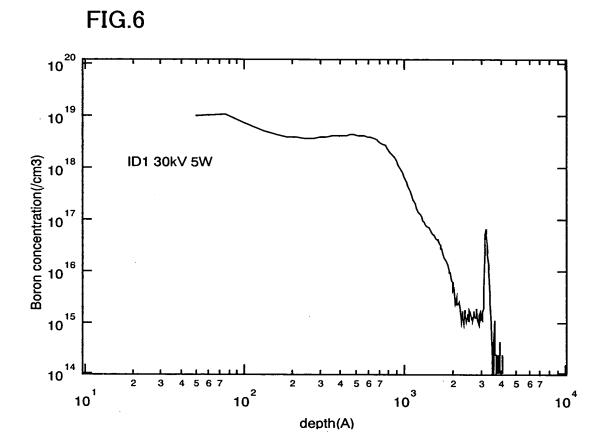
complete

401

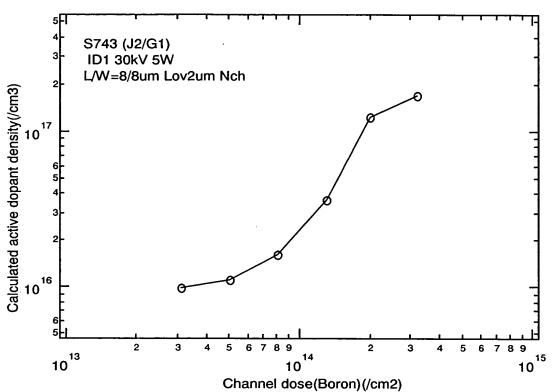
400













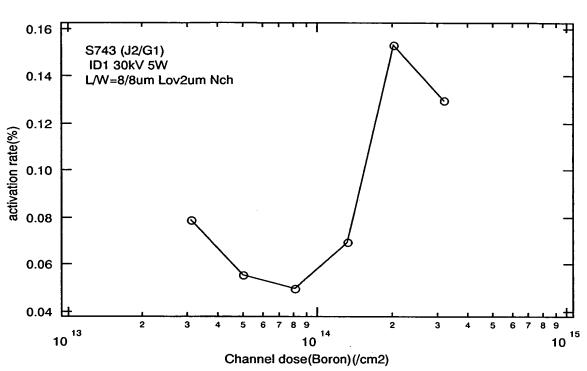
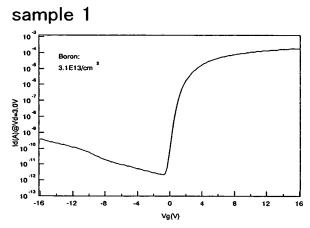
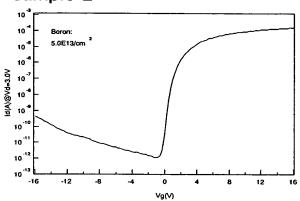


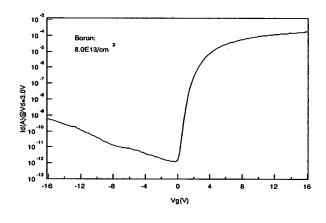
FIG.9



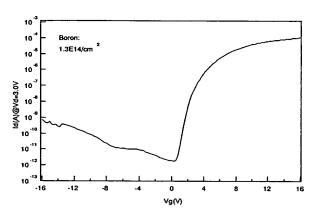
sample 2



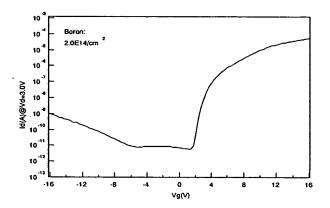
sample 3



sample 4



sample 5



sample 6

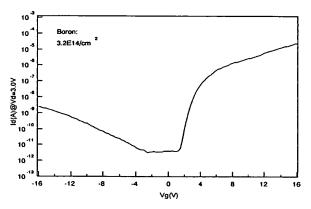


FIG.10

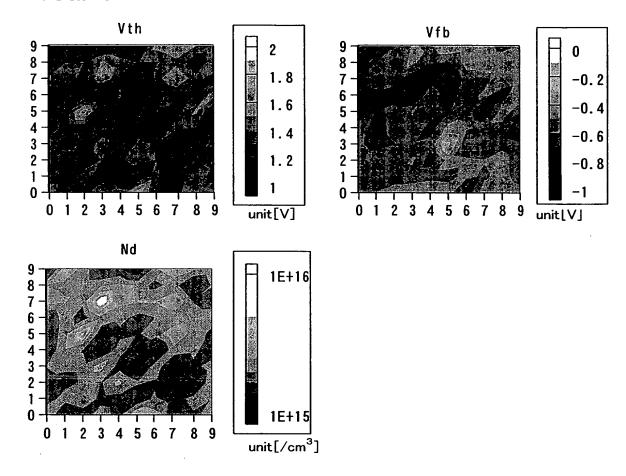


FIG.11

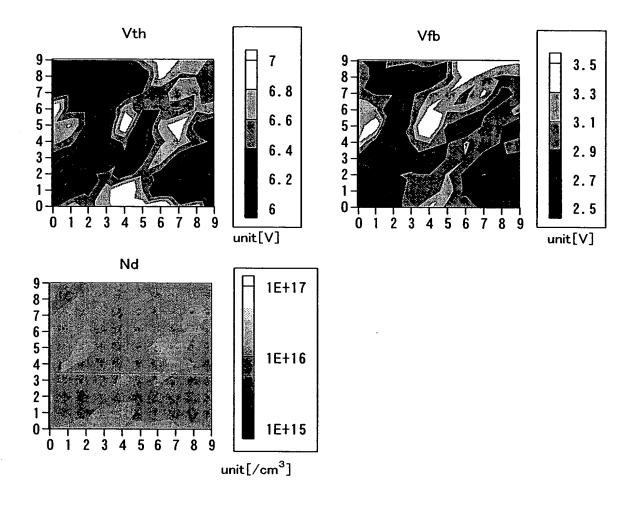


FIG.12

